NSN 5961-01-115-7387

Transistor - Page 1 of 2



View Online at https://aerobasegroup.com/nsn/5961-01-115-7387

Inclosure Material:

Metal

Overall Length:

Between 0.170 inches and 0.210 inches

Terminal Length:

0.500 inches

Overall Diameter:

Between 0.209 inches and 0.230 inches

End Application:

Test set mk39

Internal Configuration:

Junction contact

Joint Electronic Device Engineering Council/jedec/case Outline Designation:

To-72

Mounting Method:

Terminal

Terminal Circle Diameter:

0.100 inches

Features Provided:

Hermetically sealed case

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

20.0 collector to base voltage/static/emitter open and 15.0 collector to emitter voltage/static/base open and 2.0 emitter to base voltage, static, collector open

Current Rating Per Characteristic:

25.00 milliamperes source cutoff current

Power Rating Per Characteristic:

200.0 milliwatts small-signal input power, common-collector preset

Maximum Operating Tempurature Per Measurement Point:

200.0 degrees celsius junction

Special Features:

Junction pattern arrangement: npn

Precious Material And Location:

Leads gold

Precious Material:

Gold

Terminal Type And Quantity:

4 uninsulated wire lead

Shelf Life:

N/a

Unit Of Measure:

NSN 5961-01-115-7387

Transistor - Page 2 of 2

Demilitarization:

No

Fiig:

A110a0

